

2SK2963

DC-DC Converter, Relay Drive and Motor Drive Applications

- 4-V gate drive
- Low drain-source ON-resistance: $R_{DS(ON)} = 0.5 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 1.2 S$ (typ.)
- Low leakage current: $I_{DSS} = 100 \mu A$ (max) ($V_{DS} = 100 V$)
- Enhancement mode: $V_{th} = 0.8$ to $2.0 V$ ($V_{DS} = 10 V, I_D = 1 mA$)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	100	V
Drain-gate voltage ($R_{GS} = 20 k\Omega$)		V_{DGR}	100	V
Gate-source voltage		V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	1	A
	Pulse (Note 1)	I_{DP}	3	
Drain power dissipation		P_D	0.5	W
Drain power dissipation (Note 2)		P_D	1.5	W
Single pulse avalanche energy (Note 3)		E_{AS}	137	mJ
Avalanche current		I_{AR}	1	A
Repetitive avalanche energy (Note 4)		E_{AR}	0.05	mJ
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	-55 to 150	°C

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Mounted on a ceramic board (25.4 mm × 25.4 mm × 0.8 mm)

Note 3: $V_{DD} = 25 V, T_{ch} = 25^\circ C$ (initial), $L = 221 mH, R_G = 25 \Omega, I_{AR} = 1 A$

Note 4: Repetitive rating: pulse width limited by maximum junction temperature.

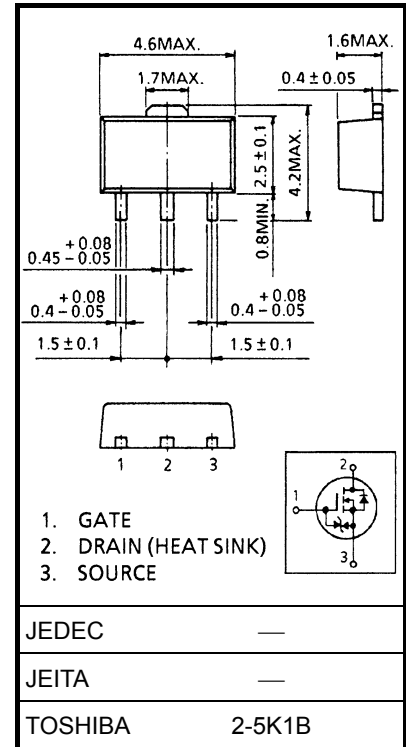
Note 5: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device.
Handle with care.

Thermal Characteristics

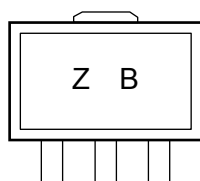
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient	$R_{th(ch-a)}$	250	°C/W

Unit: mm



Weight: 0.05 g (typ.)

Marking



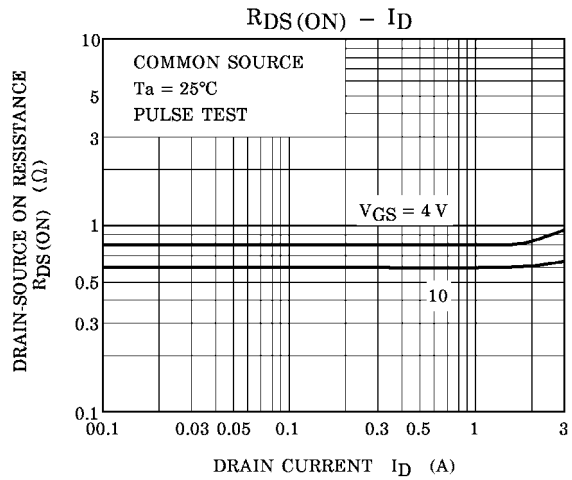
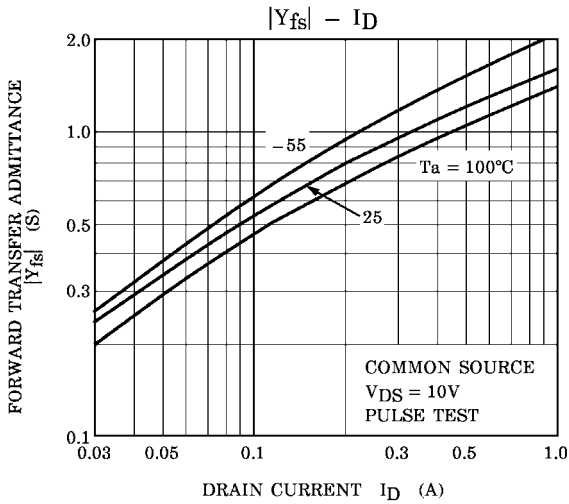
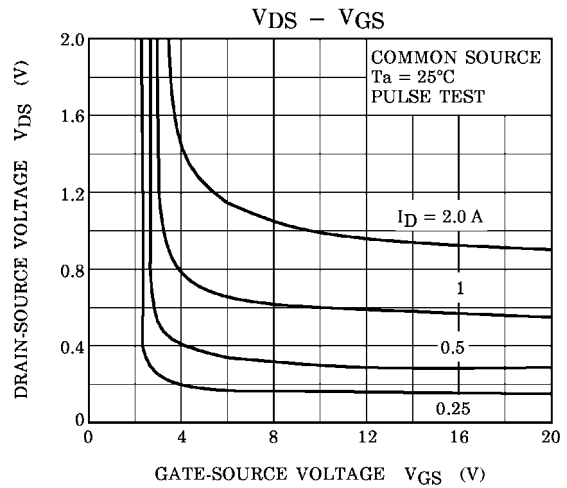
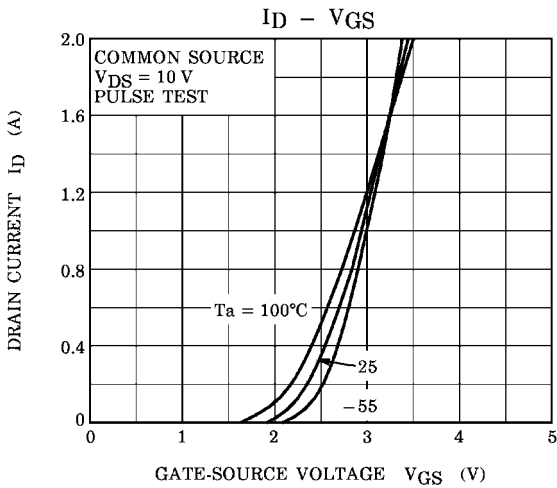
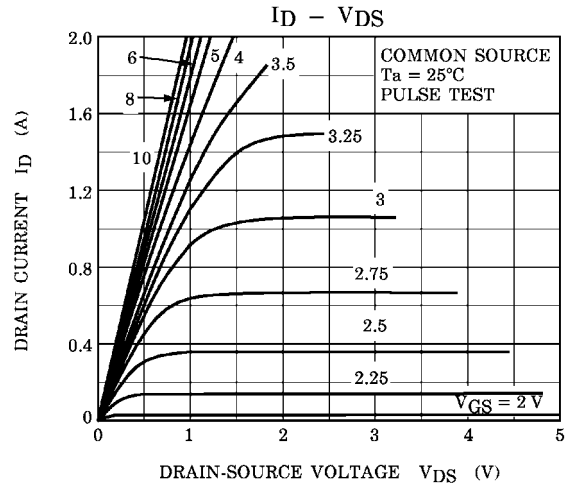
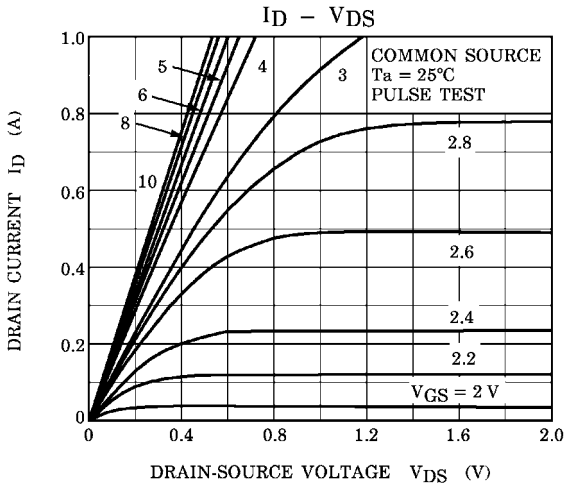
(The two digits represent the part number.)

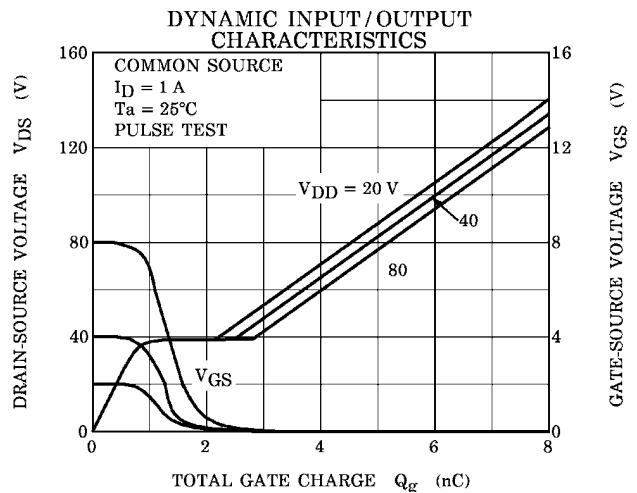
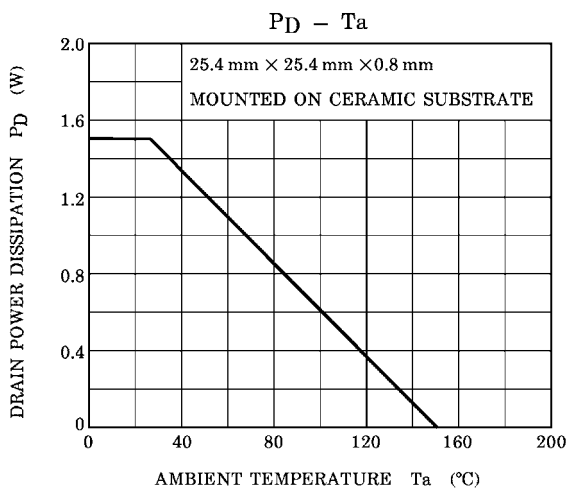
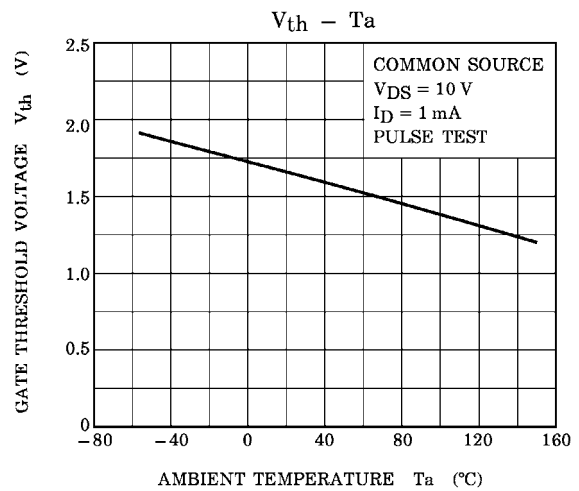
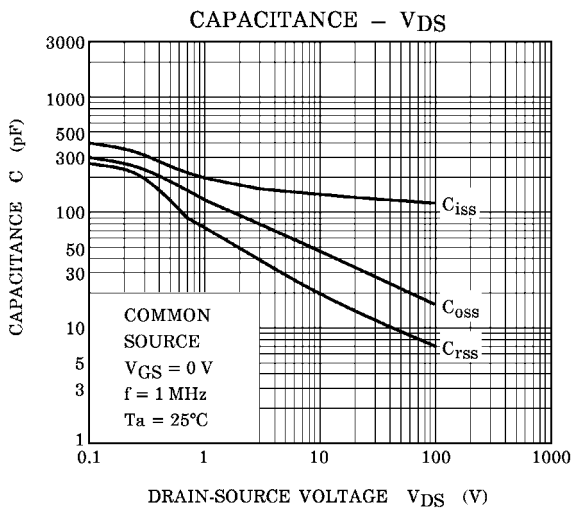
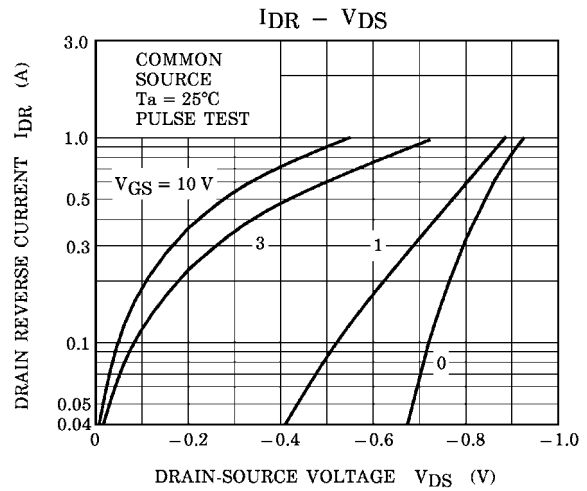
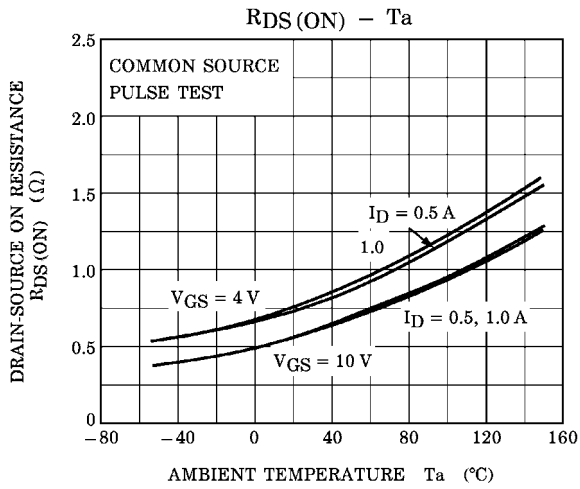
Electrical Characteristics (Ta = 25°C)

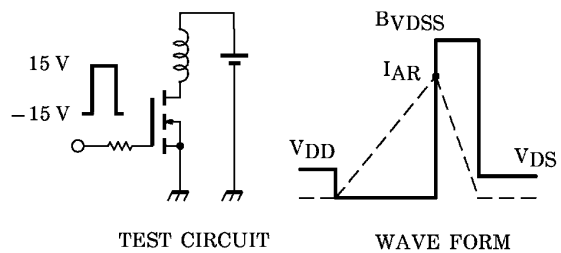
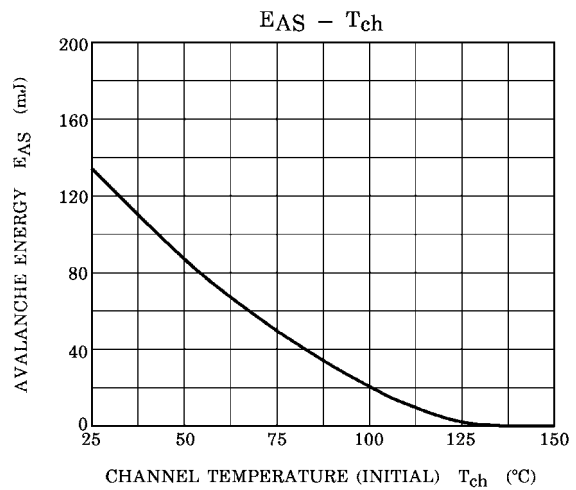
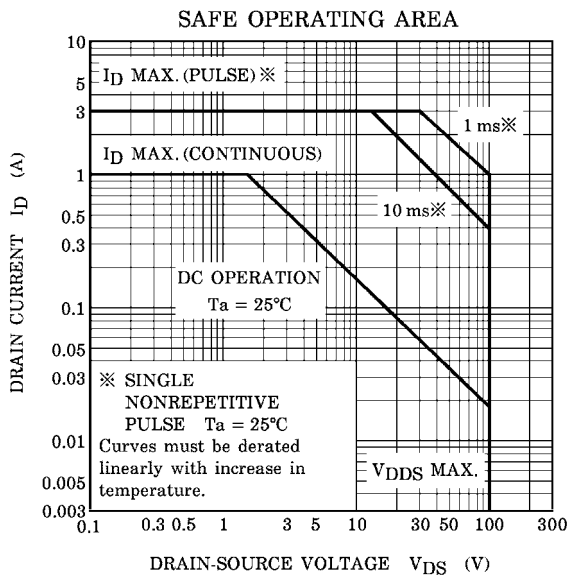
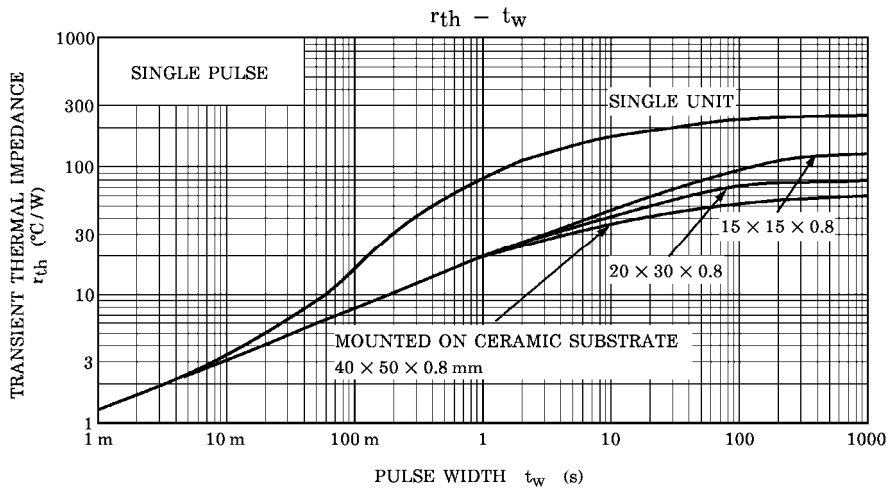
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 10	μA
Drain cut-off current		I_{DSS}	$V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}$	—	—	100	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	100	—	—	V
Gate threshold voltage		V_{th}	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	0.8	—	2.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = 4\text{ V}, I_D = 0.5\text{ A}$	—	0.65	0.95	Ω
			$V_{GS} = 10\text{ V}, I_D = 0.5\text{ A}$	—	0.5	0.7	
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 0.5\text{ A}$	0.6	1.2	—	S
Input capacitance		C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	140	—	pF
Reverse transfer capacitance		C_{rss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	20	—	pF
Output capacitance		C_{oss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	45	—	pF
Switching time	Rise time	t_r		—	8	—	ns
	Turn-on time	t_{on}		—	13	—	
	Fall time	t_f		—	45	—	
	Turn-off time	t_{off}		Duty $\leq 1\%$, $t_w = 10\ \mu\text{s}$	—	175	
Total gate charge (gate-source plus gate-drain)		Q_g	$V_{DD} \approx 80\text{ V}, V_{GS} = 10\text{ V}, I_D = 1\text{ A}$	—	6.3	—	nC
Gate-source charge		Q_{gs}	$V_{DD} \approx 80\text{ V}, V_{GS} = 10\text{ V}, I_D = 1\text{ A}$	—	4.3	—	nC
Gate-drain ("miller") charge		Q_{gd}	$V_{DD} \approx 80\text{ V}, V_{GS} = 10\text{ V}, I_D = 1\text{ A}$	—	2	—	nC

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	—	—	—	1	A
Pulse drain reverse current (Note 1)	I_{DRP}	—	—	—	3	A
Forward voltage (diode)	V_{DSF}	$I_{DR} = 1\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.5	V
Reverse recovery time	t_{rr}	$I_{DR} = 1\text{ A}, V_{GS} = 0\text{ V}, dI_{DR}/dt = 50\text{ A}/\mu\text{s}$	—	80	—	ns
Reverse recovery charge	Q_{rr}	$I_{DR} = 1\text{ A}, V_{GS} = 0\text{ V}, dI_{DR}/dt = 50\text{ A}/\mu\text{s}$	—	140	—	μC







$$R_G = 25 \Omega$$

$$V_{DD} = 25 \text{ V}, L = 221 \text{ mH} \quad E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BV_{DSS}}{BV_{DSS} - V_{DD}} \right)$$

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